

QT-Brightek Optocoupler Series

4-PIN DC Input Phototransistor Optocoupler

Part No.: QT851

| | | |
|----------------|-------------------------|--------------|
| Product: QT851 | Date: February 12, 2018 | Page 1 of 19 |
| | Version# 1.0 | |



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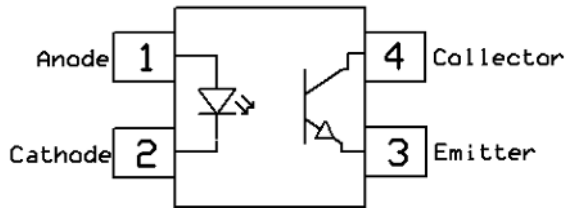
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Introduction

Feature:

- High Isolation voltage between input and output (Viso = 5000V rms)
- Creepage distance $\geq 7.5\text{mm}$ (S/SL Type)
- Creepage distance $\geq 8.0\text{mm}$ (SLM Type)
- Operating Temperature up to $100\text{ }^\circ\text{C}$
- Available in Tube or Tape and reel
- Available with standard DIP-4, Gullwing lead bend, SMD lead bend, SMD low profile and SMD Gullwing options.

Schematic:



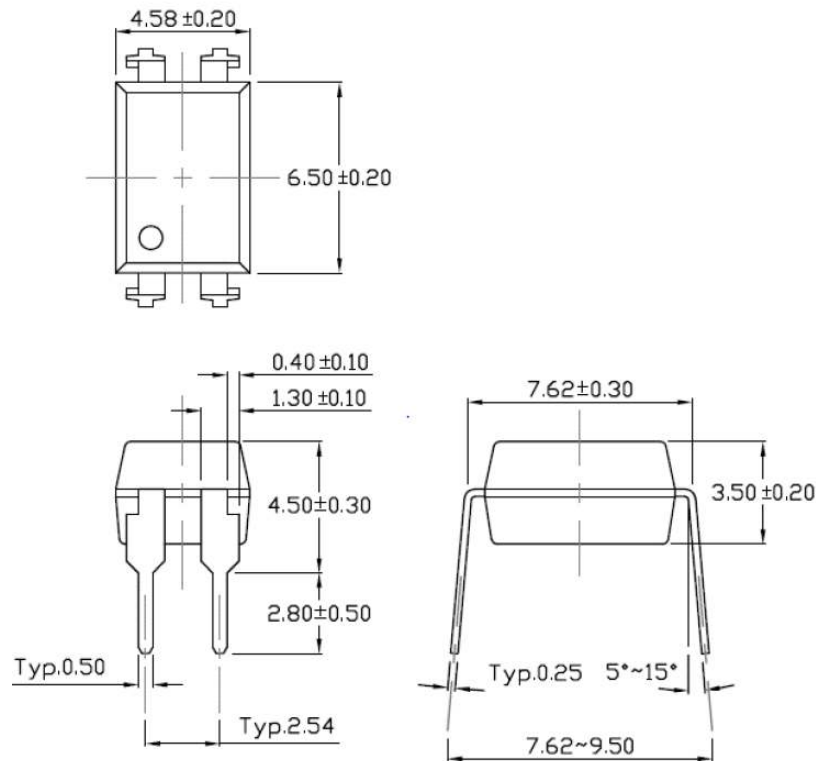
Certification & Compliance:

- Pb free and RoHS Compliant
- UL recognized (File #E338132)
- cUL recognized (File #E338132)
- VDE (Pending Approval)

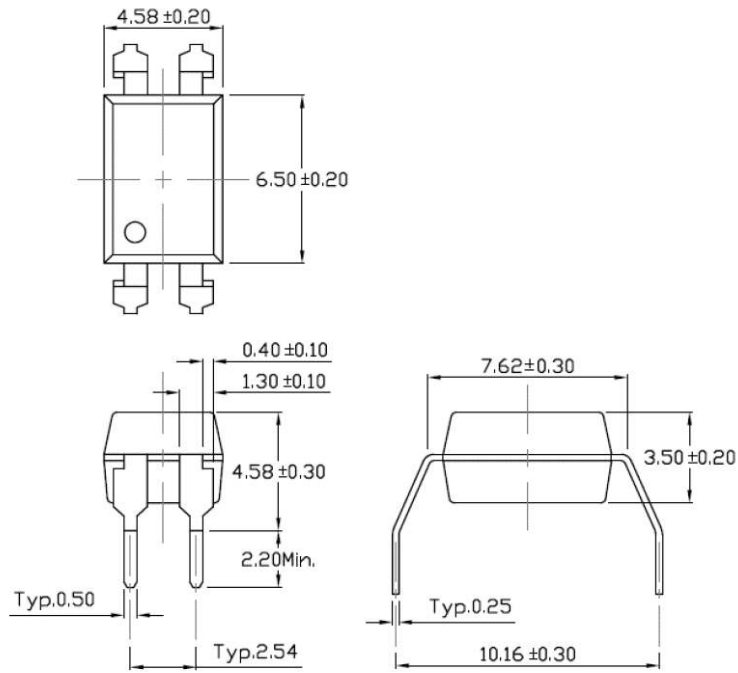


Dimension: (Dot location indicates pin 1)

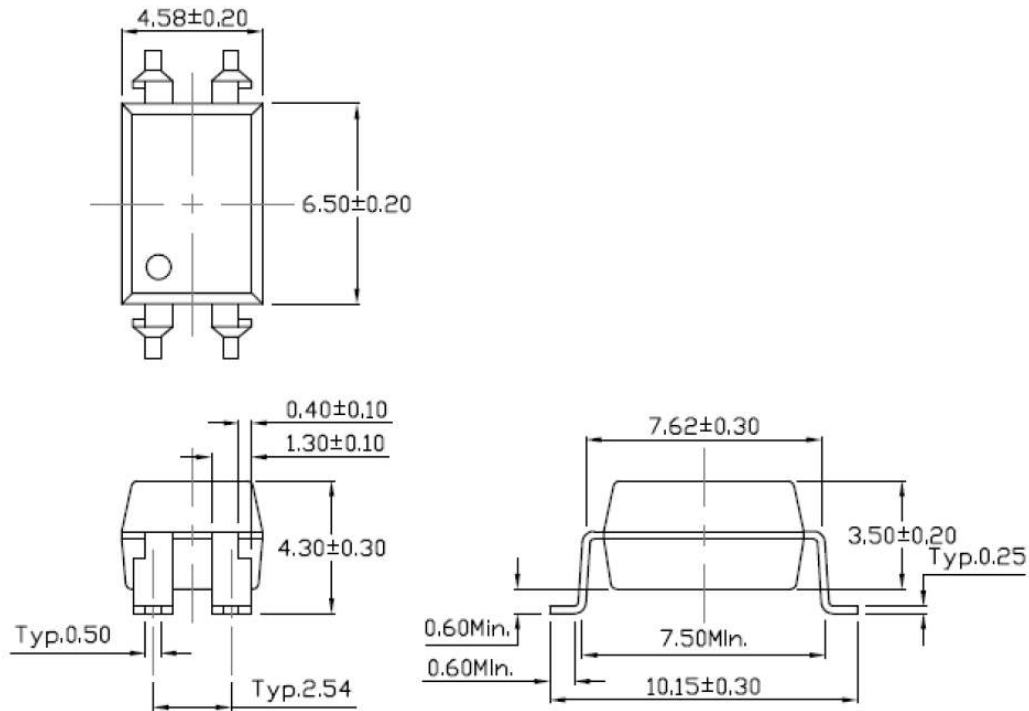
4-Pin Dip (standard):



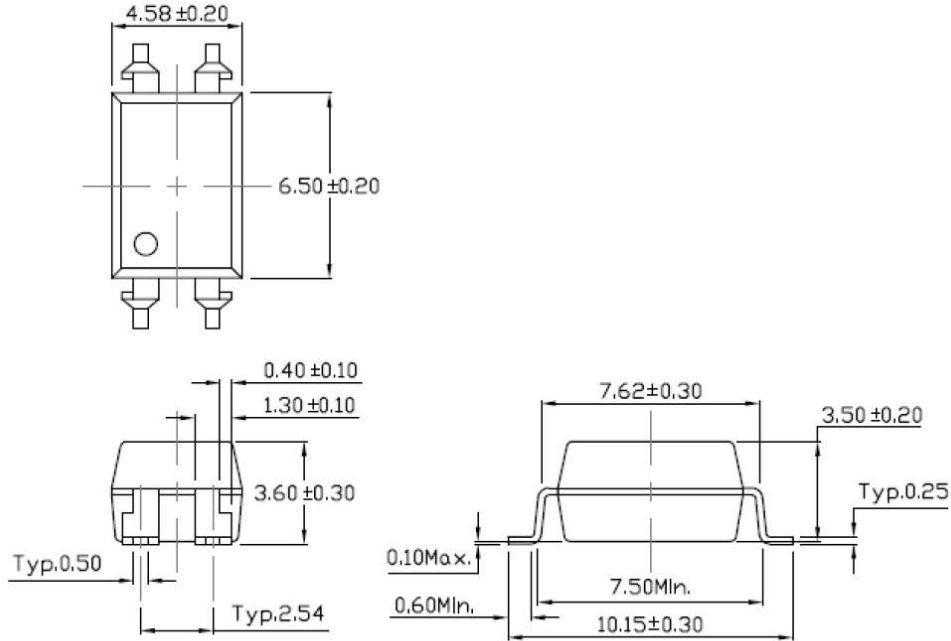
Gullwing (400mil) lead bend (Option M):



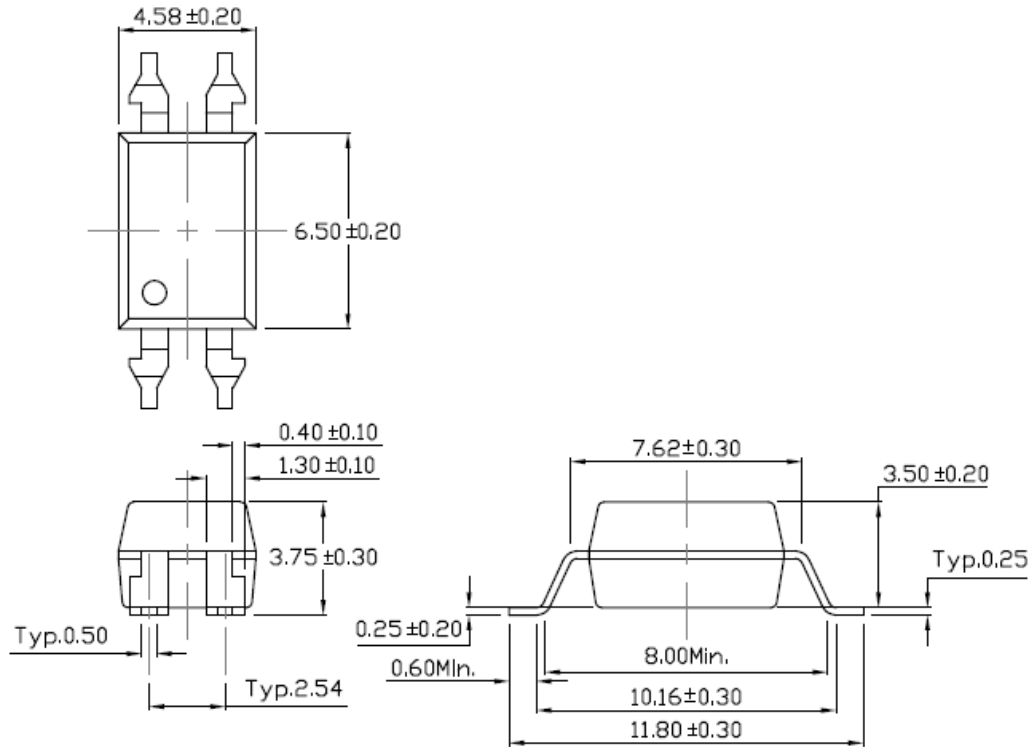
SMD lead bend (Option S):



SMD (Low Profile) bend (Option SL):



SMD (Gullwing) bend (Option SLM):



All Dimensions are in mm

Absolute Maximum Rating

| Symbol | Parameter | Rating | Units |
|-------------------|--------------------------------------|----------------|------------------|
| V _{ISO} | Isolation voltage (AC, 1 minute) | 5000 | V _{RMS} |
| T _{STG} | Storage Temperature | -55 ~ 150 | °C |
| T _{OPR} | Operating Temperature | -55 ~ 100 | °C |
| T _{SOL} | Lead Solder Temperature | 260 for 10 sec | °C |
| P _{TOT} | Total Power Dissipation | 260 | mW |
| EMITTER | | | |
| I _F | Continuous Forward Current | 80 | mA |
| I _{FP} | Peak Forward Current (≤ 1us, 300pps) | 1 | A |
| V _R | Reverse Voltage | 6 | V |
| P _D | Power Dissipation | 150 | mW |
| DETECTOR | | | |
| B _{VCEO} | Collector–Emitter Breakdown Voltage | 350 | V |
| B _{VECO} | Emitter-Collector Breakdown Voltage | 7 | V |
| I _C | Continuous Collector Current | 100 | mA |
| P _C | Collector Power Dissipation | 300 | mW |

Electrical Characteristic (T_A=25 °C)

Emitter

| Symbol | Characteristic | Test Condition | Range | | | Unit |
|-----------------|-------------------|-----------------------|-------|-----|-----|------|
| | | | Min | Typ | Max | |
| V _F | Forward Voltage | I _F = 10mA | - | 1.2 | 1.4 | V |
| I _R | Reverse Current | V _R = 6V | - | - | 10 | μA |
| C _{IN} | Input Capacitance | f = 1MHz | - | 30 | - | pF |

Detector

| Symbol | Characteristic | Test Condition | Range | | | Unit |
|-------------------|--|--|-------|-----|-----|------|
| | | | Min | Typ | Max | |
| I _{CEO} | Collector-Emitter Dark current | V _{CE} = 20V, I _F = 0mA | - | - | 100 | nA |
| BV _{CEO} | Collector-Emitter breakdown voltage | I _C = 100 μA | 350 | - | - | V |
| BV _{ECO} | Emitter-Collector breakdown voltage | I _E = 100 μA | 7 | - | - | V |

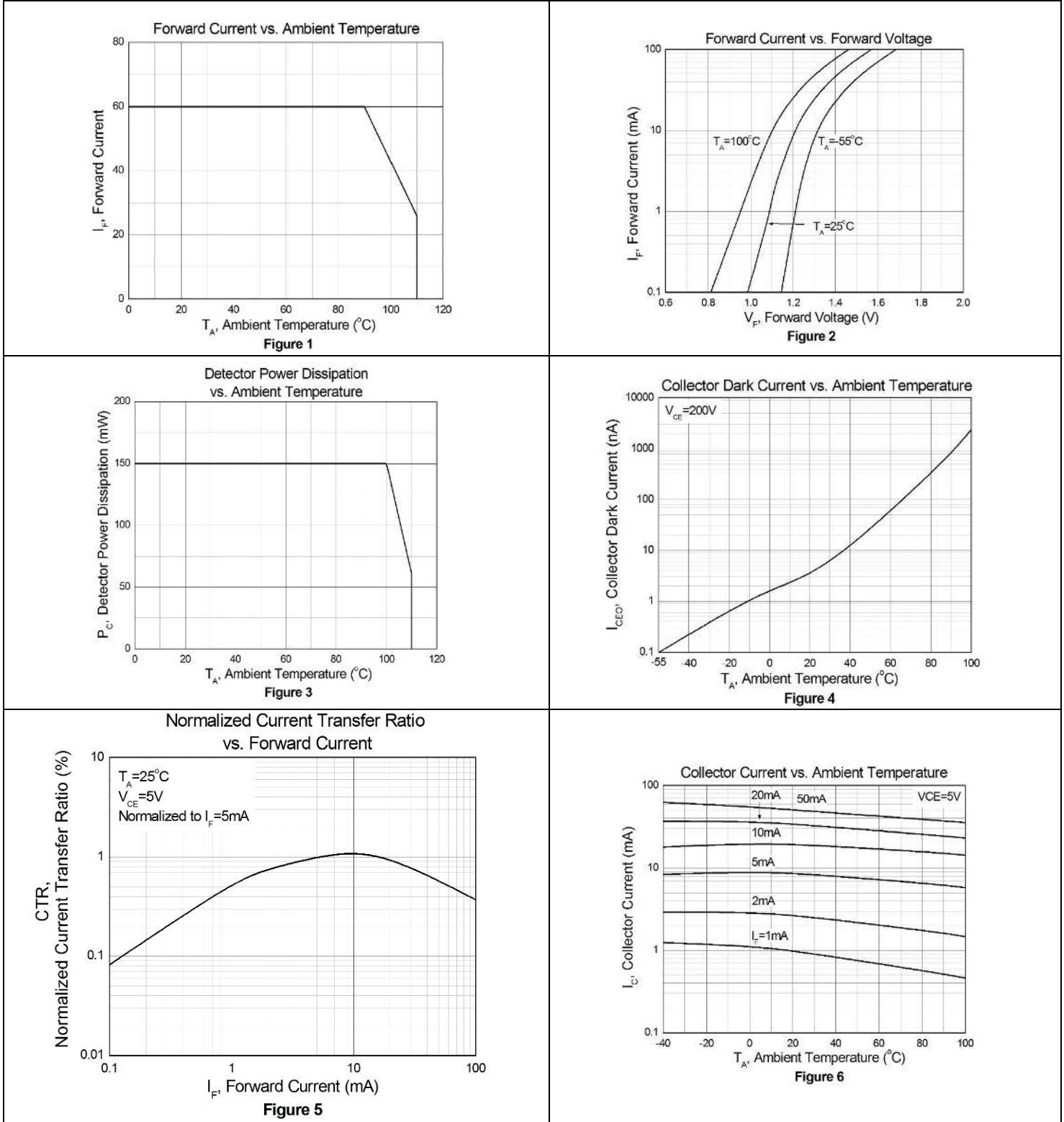
DC Transfer Characteristic

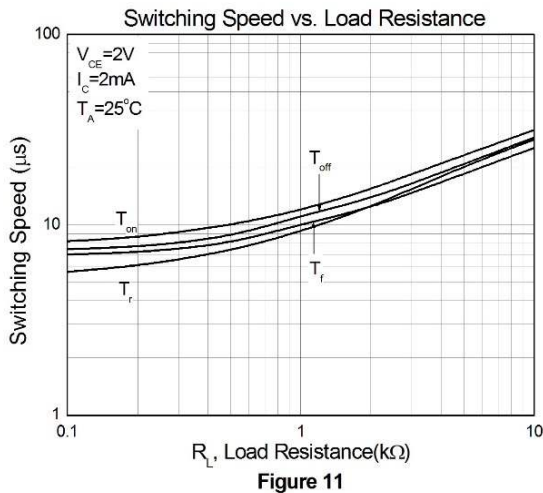
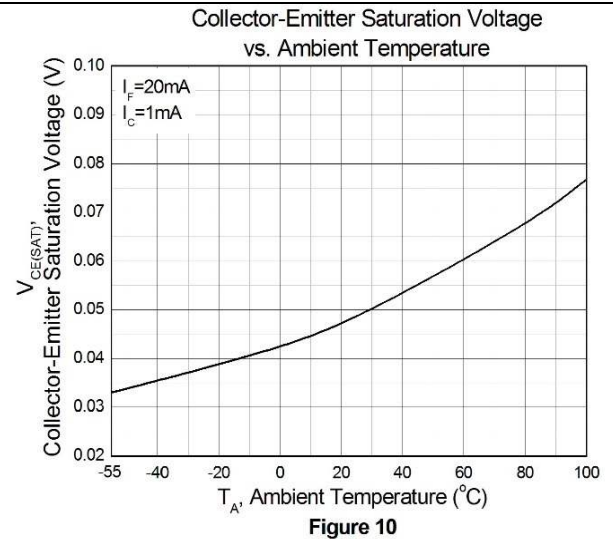
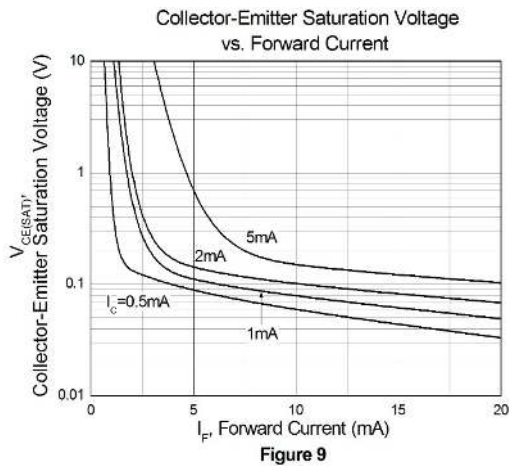
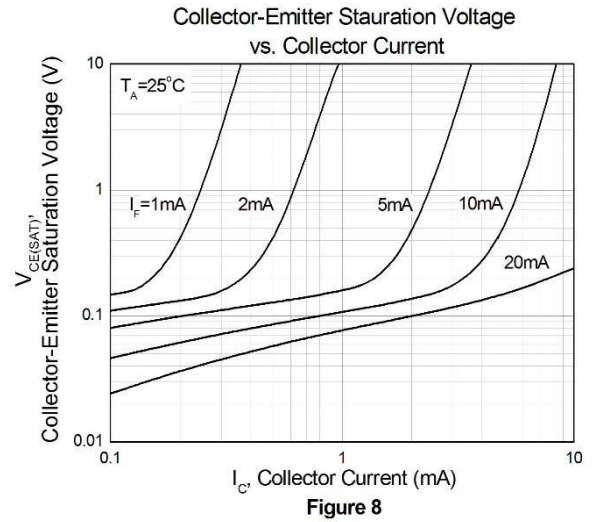
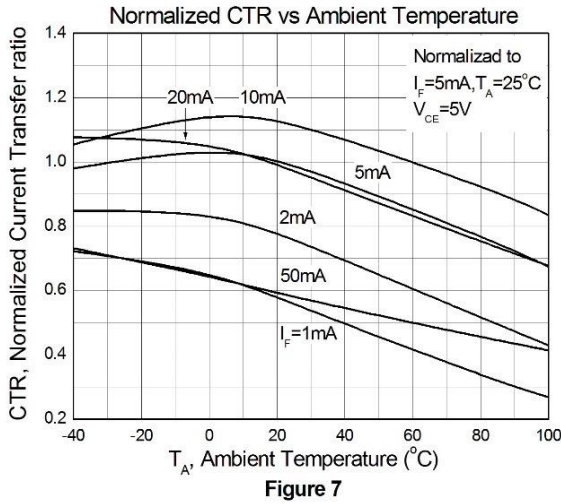
| Symbol | Characteristic | Test Condition | Range | | | Unit |
|----------------------|--|--|--------------------|-----|-----|------|
| | | | Min | Typ | Max | |
| CTR | Current Transfer Ratio | I _F = 5mA, V _{CE} = 5V | 50 | - | 600 | % |
| V _{CE(Sat)} | Collector- Emitter saturation voltage | I _F = 20mA, I _C = 1mA | - | - | 0.4 | V |
| R _{IO} | Isolation Resistance | V _{IO} = 500V _{DC} | 5X10 ¹⁰ | - | - | Ω |
| C _{IO} | Isolation Capacitance | f = 1MHz | - | 0.5 | 1.0 | pF |

AC Characteristic

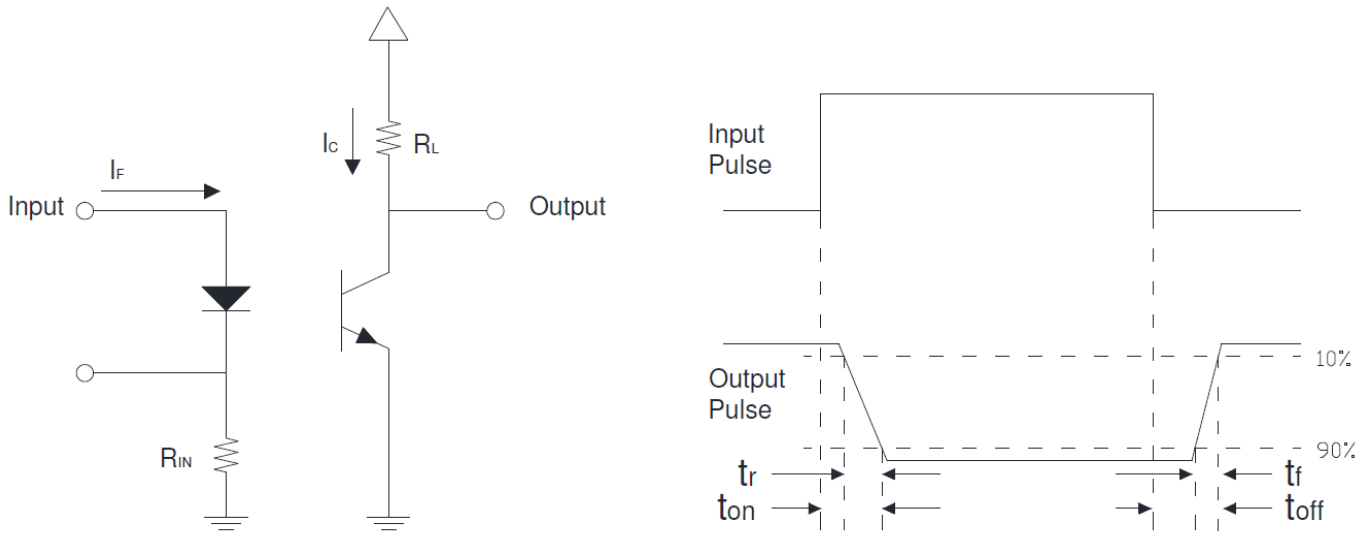
| Symbol | Characteristic | Test Condition | Range | | | Unit |
|----------------|----------------|---|-------|-----|-----|------|
| | | | Min | Typ | Max | |
| t _r | Rise time | V _{CE} = 2V, I _C = 2mA, R _L = 100Ω | - | 6 | - | μs |
| t _f | Fall time | | - | 8 | - | |

Characteristic Curves





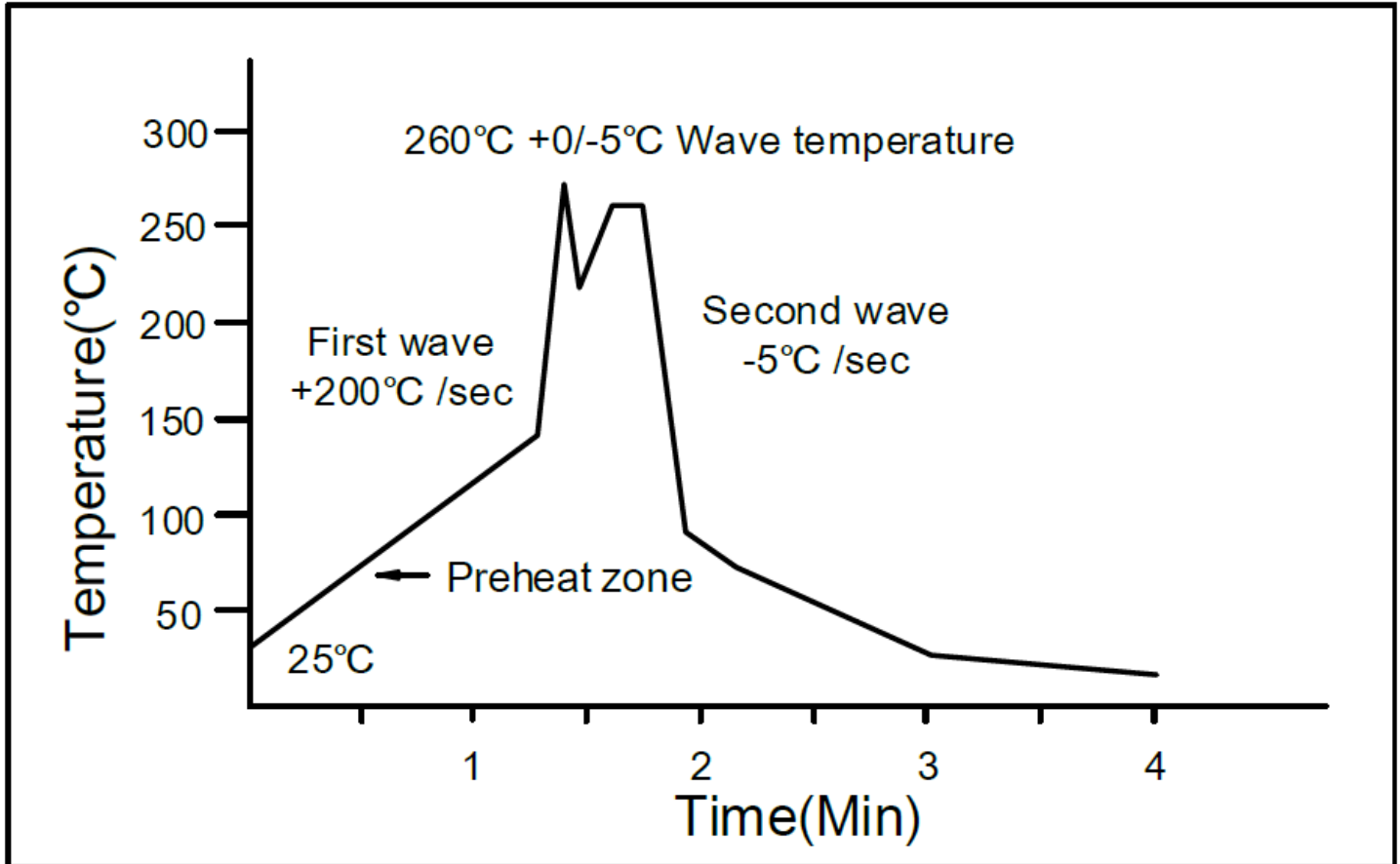
Test Circuit for Response Time



Switching Time Test Circuits

Solder Profile & Footprint

Wave soldering



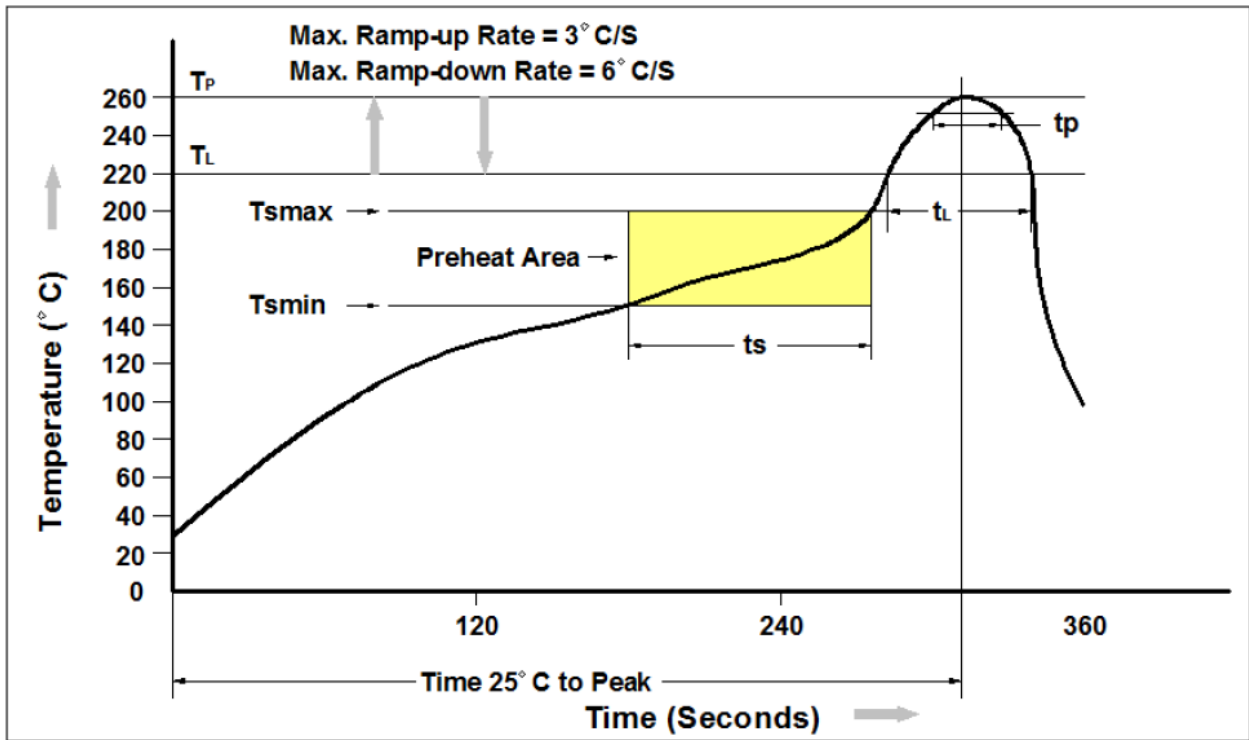
Temperature: 260 +0/-5 °C

Time: 10 Sec

Preheat temperature: 25 to 140 °C

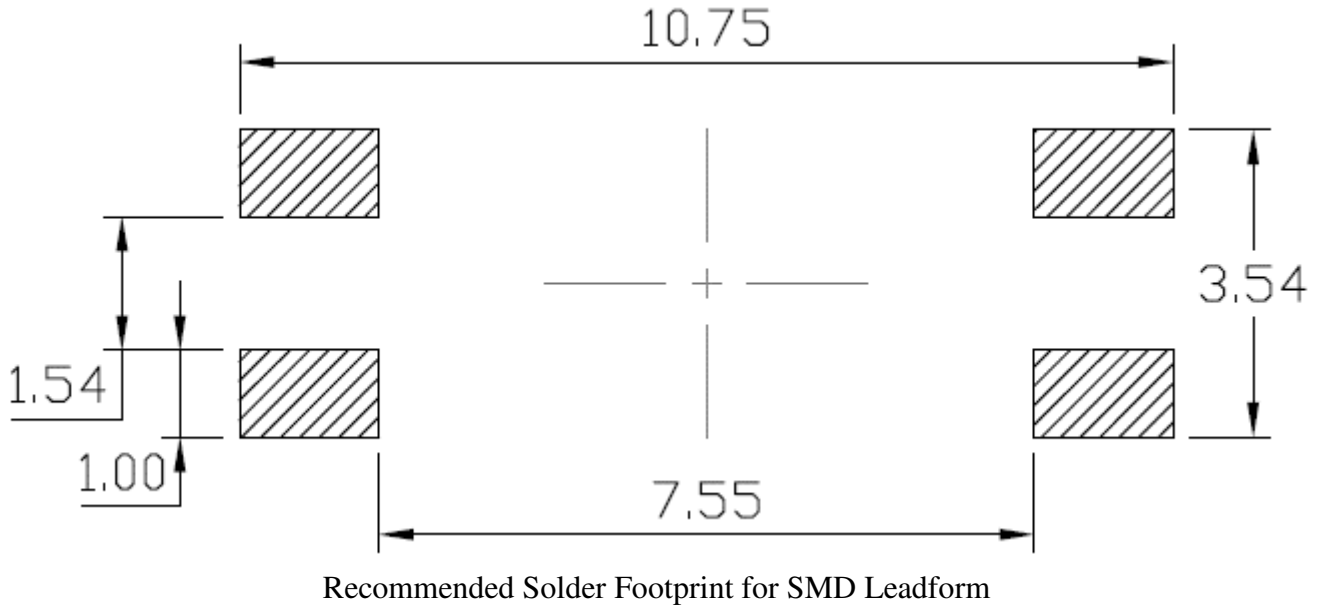
Preheat time: 30 to 80 sec.

Reflow soldering



| Profile Feature | Pb-Free Assembly Profile |
|---|--------------------------|
| Temperature Min. (T _{smin}) | 150°C |
| Temperature Max. (T _{smax}) | 200°C |
| Time (t _s) from (T _{smin} to T _{smax}) | 60-120 seconds |
| Ramp-up Rate (t _L to t _P) | 3°C/second max. |
| Liquidous Temperature (T _L) | 217°C |
| Time (t _L) Maintained Above (T _L) | 60 – 150 seconds |
| Peak Body Package Temperature | 260°C +0°C / -5°C |
| Time (t _P) within 5°C of 260°C | 30 seconds |
| Ramp-down Rate (T _P to T _L) | 6°C/second max |
| Time 25°C to Peak Temperature | 8 minutes max. |

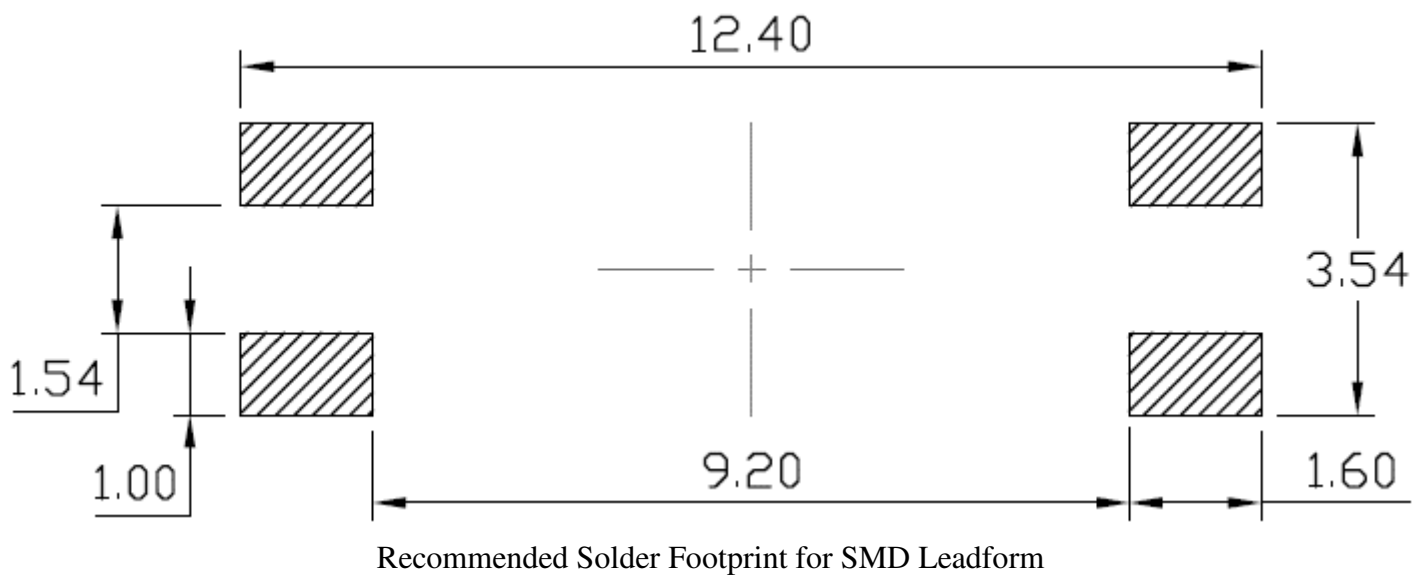
SMD lead bend (Option S) & SMD (Low Profile) bend (Option SL):



Units: mm

tolerance: +/- 0.1mm

SMD (Gullwing) bend (Option SLM):

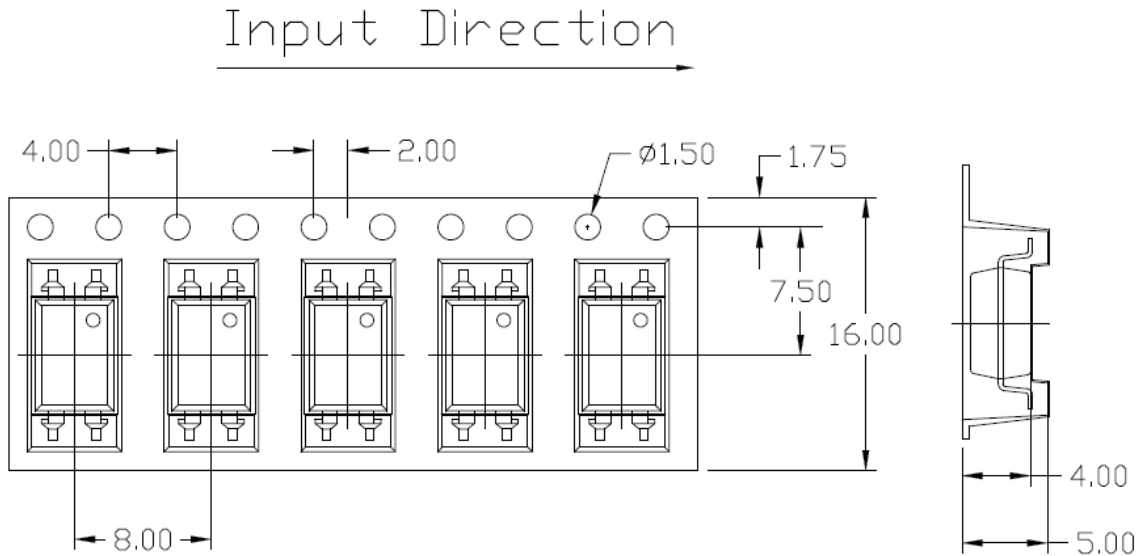


Units: mm

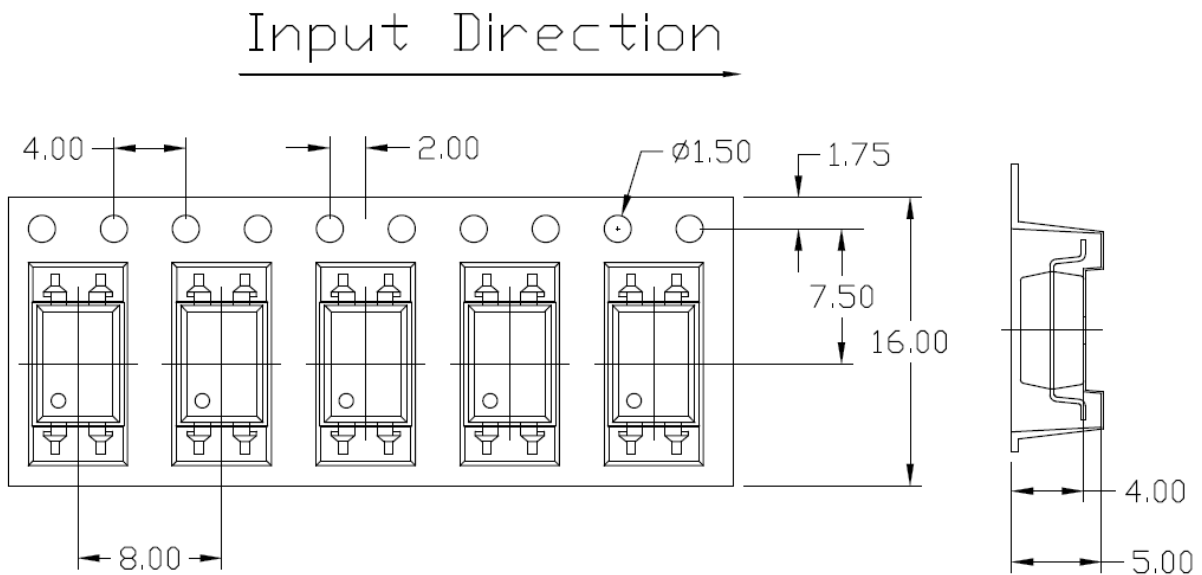
tolerance: +/- 0.1mm

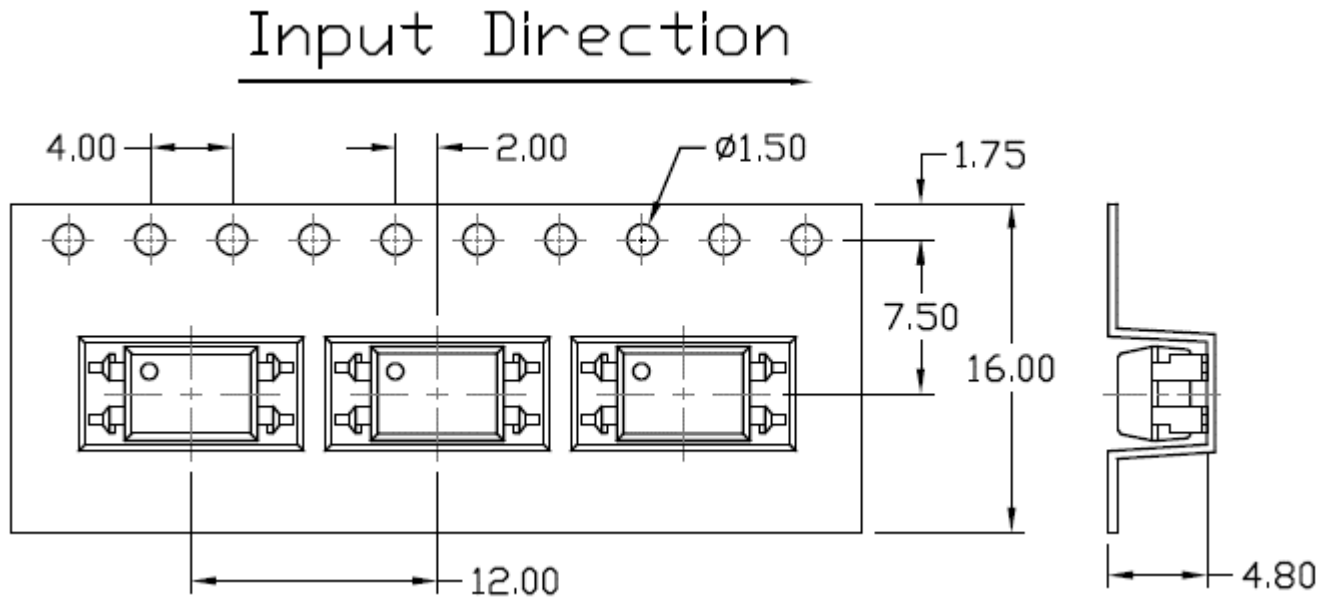
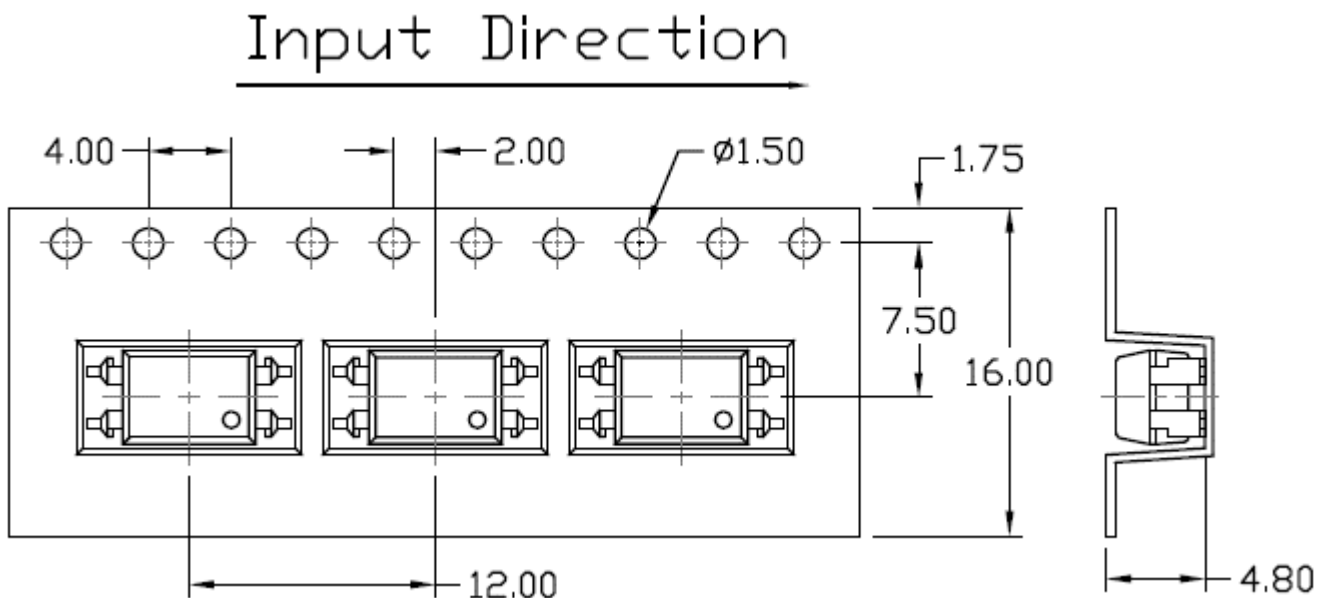
Packing & Labeling

Option S(T1) & SL(T1)



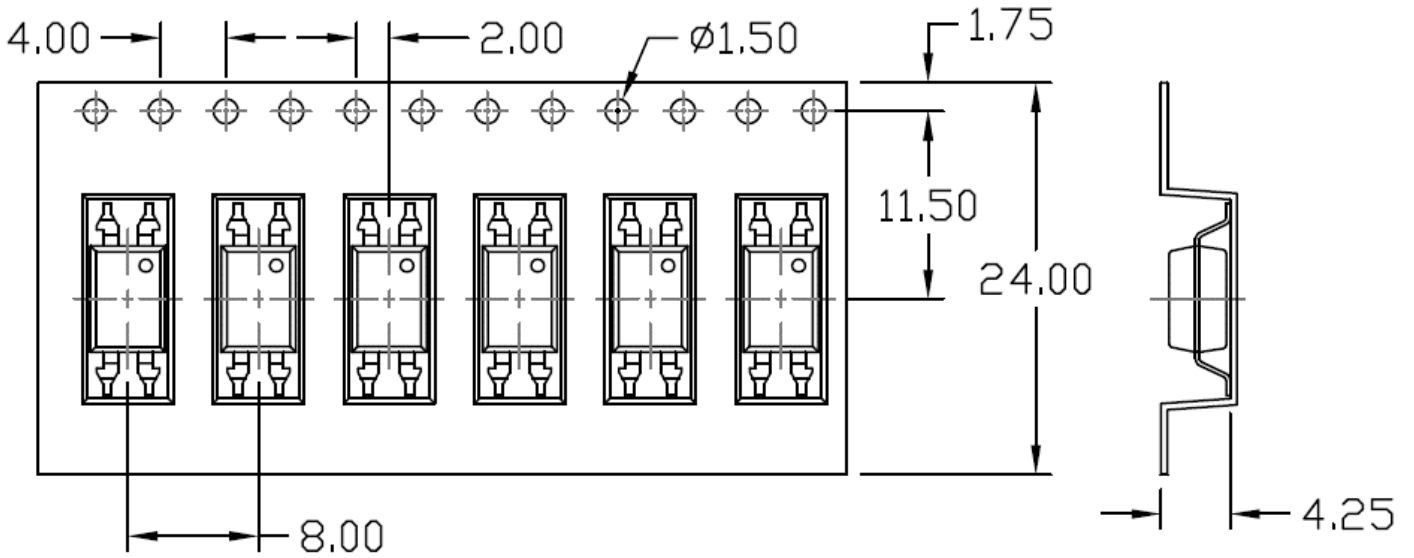
Option S(T2) & SL(T2)



Option S(T3) & SL(T3)**Option S(T4) & SL(T4)**

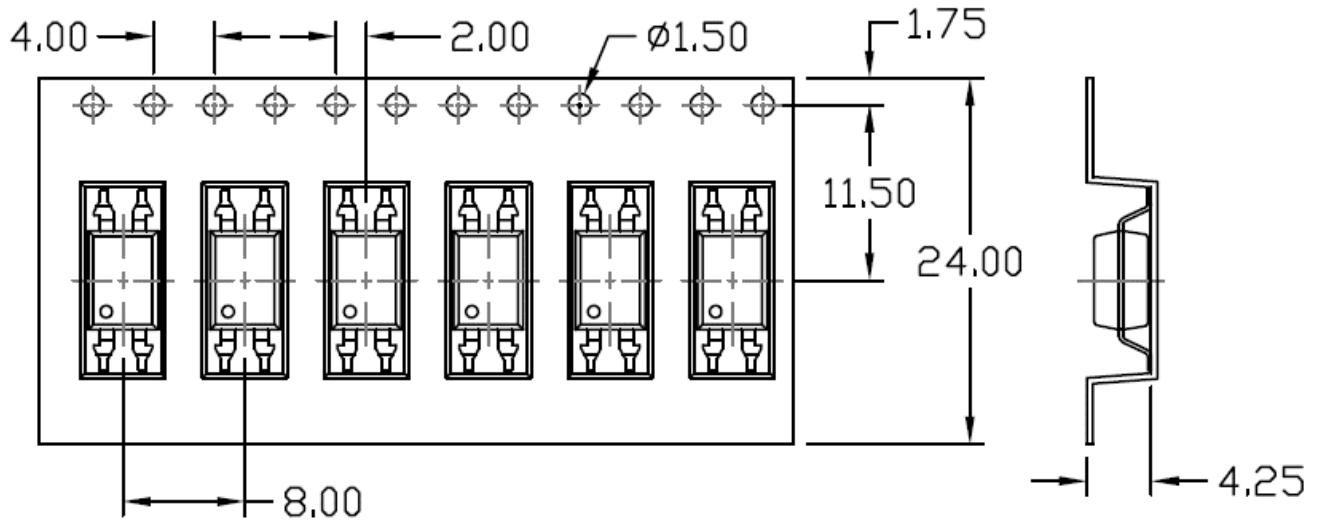
Option SLM(T1)

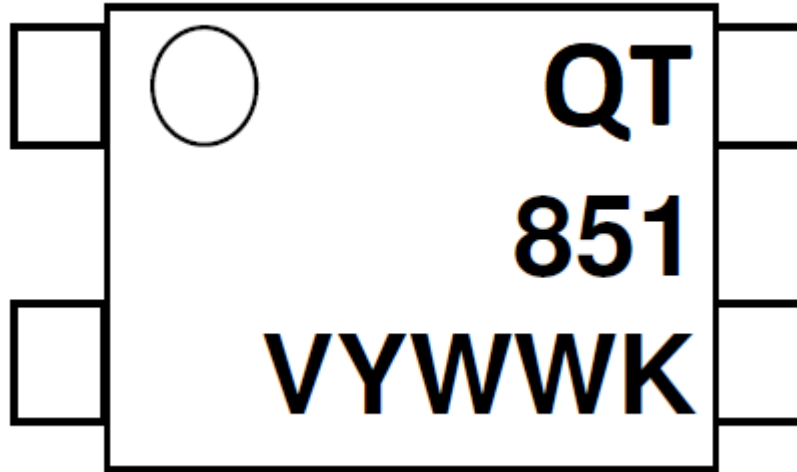
Input Direction
→



Option SLM(T2)

Input Direction
→



Device Marking

QT = QT-Brightek Corporation

851 = part number

Y = Year

WW = Week

V = VDE Option

K = Manufacturing code

Ordering Information

QT851(V)(Y)(Z)

V = VDE option (V or None)

Y = Lead form option (S, SL, M, SLM)

Z=Tape and reel option (T1, T2, T3, T4 or none)

| Option | Description | Quantity |
|---------|---|----------------|
| None | Standard 4-Pin DIP | 100 Units/Tube |
| M | Gullwing | 100 Units/Tube |
| S(T1) | Surface Mount Lead Forming – with Option 1 Taping | 1500 pcs/ reel |
| S(T2) | Surface Mount Lead Forming – with Option 2 Taping | 1500 pcs/ reel |
| S(T3) | Surface Mount Lead Forming – with Option 3 Taping | 1000 pcs/ reel |
| S(T4) | Surface Mount Lead Forming – with Option 4 Taping | 1000 pcs/ reel |
| SL(T1) | SMD (Low Profile) Lead Forming – with Option 1 Taping | 1500 pcs/ reel |
| SL(T2) | SMD (Low Profile) Lead Forming – with Option 2 Taping | 1500 pcs/ reel |
| SL(T3) | SMD (Low Profile) Lead Forming – with Option 3 Taping | 1000 pcs/ reel |
| SL(T4) | SMD (Low Profile) Lead Forming – with Option 4 Taping | 1000 pcs/ reel |
| SLM(T1) | SMD (Gullwing) Lead Forming – with Option 1 Taping | 1500 pcs/ reel |
| SLM(T2) | SMD (Gullwing) Lead Forming – with Option 2 Taping | 1500 pcs/ reel |



Revision History

| Description: | Revision # | Revision Date |
|--------------------------|------------|---------------|
| Initial release of QT851 | 1.0 | 02/12/2018 |
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Disclaimer

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2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.